

## PROTECTION PRODUCTS - MicroClamp™

### Description

The  $\mu$ Clamp™ series of Transient Voltage Suppressors (TVS) are designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDAs. They offer superior electrical characteristics such as lower clamping voltage and no device degradation when compared to MLVs. They are designed to protect sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD), lightning, electrical fast transients (EFT), and cable discharge events (CDE).

The  $\mu$ Clamp™3301H is constructed using Semtech's proprietary EPD process technology. The EPD process provides low standoff voltages with significant reductions in leakage currents and capacitance over silicon-avalanche diode processes. They feature a true operating voltage of 3.3 volts for superior protection when compared to traditional pn junction devices.

The  $\mu$ Clamp3301H is in a SOD-523 package and will protect one unidirectional line. They give the designer the flexibility to protect one line in applications where arrays are not practical.

They may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 ( $\pm 15$ kV air,  $\pm 8$ kV contact discharge).

### Features

- ◆ Transient protection for data lines to **IEC 61000-4-2 (ESD)  $\pm 20$ kV (air),  $\pm 10$ kV (contact)**  
**IEC 61000-4-4 (EFT) 40A (tp = 5/50ns)**  
**Cable Discharge Event (CDE)**
- ◆ Ultra-small SOD-523 package (1.7 x 0.9 x 0.7mm)
- ◆ Protects one I/O or power line
- ◆ Low clamping voltage
- ◆ Working voltage: 3.3V
- ◆ Low leakage current
- ◆ Solid-state silicon-avalanche technology

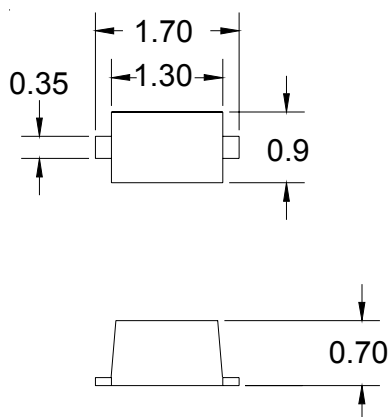
### Mechanical Characteristics

- ◆ EIAJ SOD-523 package
- ◆ Molding compound flammability rating: UL 94V-0
- ◆ Marking : Marking code, cathode band
- ◆ Packaging: Tape and Reel
- ◆ Lead Finish: Matte tin

### Applications

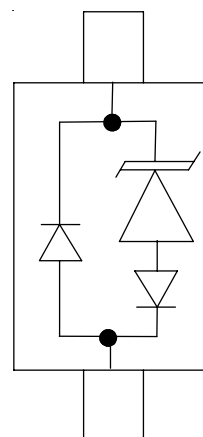
- ◆ Cellular Handsets & Accessories
- ◆ Cordless Phones
- ◆ Personal Digital Assistants (PDAs)
- ◆ Notebooks & Handhelds
- ◆ Portable Instrumentation
- ◆ Digital Cameras
- ◆ Peripherals
- ◆ MP3 Players

### Dimensions



**Maximum Dimensions (mm)**

### Schematic & PIN Configuration



**SOD-523 (Top View)**

## PROTECTION PRODUCTS

### Absolute Maximum Rating

| Rating                                                         | Symbol           | Value            | Units |
|----------------------------------------------------------------|------------------|------------------|-------|
| Peak Pulse Power (tp = 8/20μs)                                 | P <sub>pk</sub>  | 40               | Watts |
| Maximum Peak Pulse Current (tp = 8/20μs)                       | I <sub>pp</sub>  | 5                | Amps  |
| ESD per IEC 61000-4-2 (Air)<br>ESD per IEC 61000-4-2 (Contact) | V <sub>pp</sub>  | +/- 20<br>+/- 15 | kV    |
| Lead Soldering Temperature                                     | T <sub>L</sub>   | 260 (10 sec.)    | °C    |
| Operating Temperature                                          | T <sub>J</sub>   | -55 to +125      | °C    |
| Storage Temperature                                            | T <sub>STG</sub> | -55 to +150      | °C    |

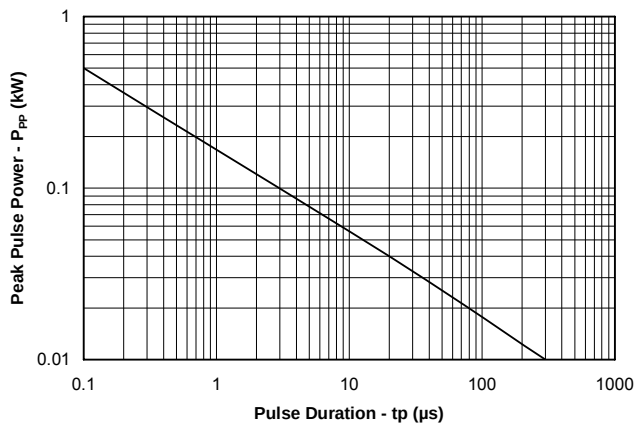
### Electrical Characteristics (T=25°C)

| Parameter                 | Symbol           | Conditions                                        | Minimum | Typical | Maximum | Units |
|---------------------------|------------------|---------------------------------------------------|---------|---------|---------|-------|
| Reverse Stand-Off Voltage | V <sub>RWM</sub> |                                                   |         |         | 3.3     | V     |
| Punch-Through Voltage     | V <sub>PT</sub>  | I <sub>PT</sub> = 2μA                             | 3.5     | 3.9     | 4.6     | V     |
| Snap-Back Voltage         | V <sub>SB</sub>  | I <sub>SB</sub> = 50mA                            | 2.8     |         |         | V     |
| Reverse Leakage Current   | I <sub>R</sub>   | V <sub>RWM</sub> = 3.3V                           |         | 0.05    | 0.5     | μA    |
| Clamping Voltage          | V <sub>C</sub>   | I <sub>pp</sub> = 1A, tp = 8/20μs                 |         |         | 5.5     | V     |
| Clamping Voltage          | V <sub>C</sub>   | I <sub>pp</sub> = 5A, tp = 8/20μs                 |         |         | 8.0     | V     |
| Forward Voltage           | V <sub>F</sub>   | I <sub>pp</sub> = 1A, tp = 8/20μs                 |         |         | 2.4     | V     |
| Junction Capacitance      | C <sub>j</sub>   | I/O pin to Gnd<br>V <sub>R</sub> = 0V, f = 1MHz   |         | 25      | 30      | pF    |
|                           |                  | I/O pin to Gnd<br>V <sub>R</sub> = 3.3V, f = 1MHz |         | 14      |         | pF    |

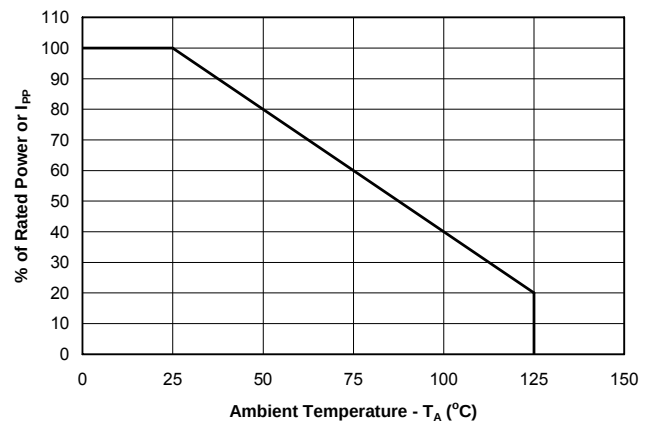
## PROTECTION PRODUCTS

### Typical Characteristics

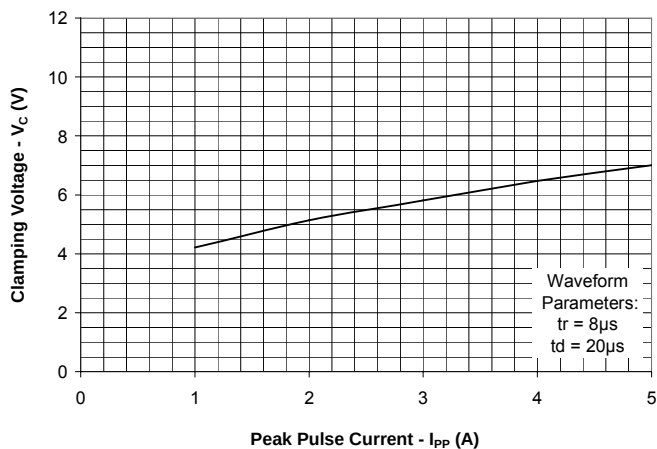
#### Non-Repetitive Peak Pulse Power vs. Pulse Time



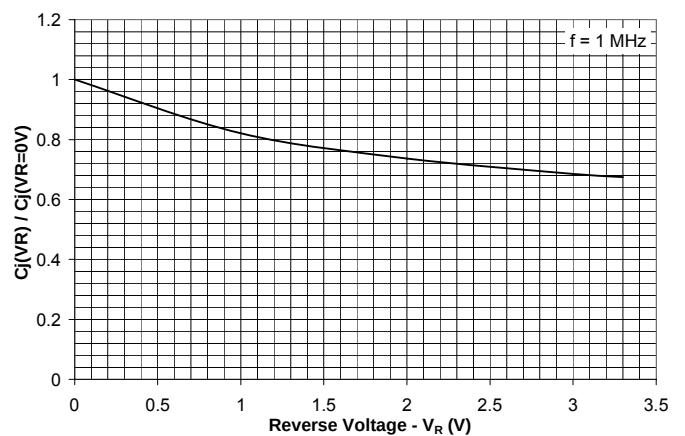
#### Power Derating Curve



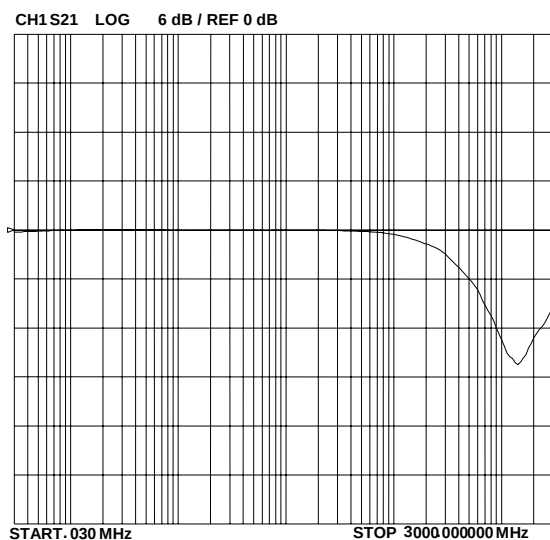
#### Clamping Voltage vs. Peak Pulse Current



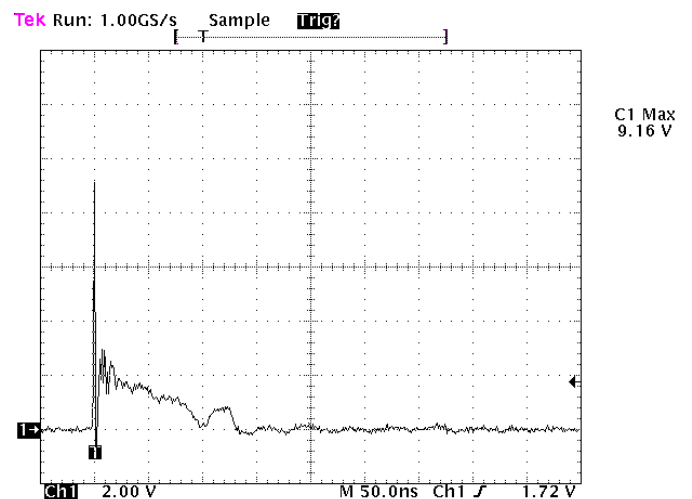
#### Junction Capacitance vs. Reverse Voltage



#### Insertion Loss S21



#### ESD Clamping (8kV Contact per IEC 61000-4-2)



Note: Data is taken with a 10x attenuator

## PROTECTION PRODUCTS

### Applications Information

#### Device Connection Options

The  $\mu$ Clamp3301H is designed to protect one I/O, or power supply line. It will present a high impedance to the protected line up to 3.3 volts. It will “turn on” when the line voltage exceeds 3.5 volts. The device is unidirectional and may be used on lines where the signal polarity is above ground. The cathode band should be placed towards the line that is to be protected.

Due to the “snap-back” characteristics of the low voltage TVS, it is not recommended that the I/O line be directly connected to a DC source greater than snap-back voltage ( $V_{SB}$ ) as the device can latch on as described below.

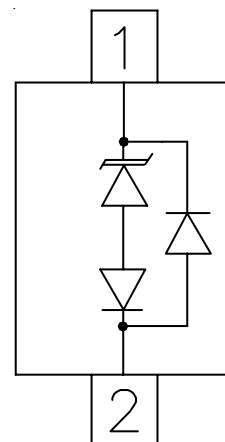
#### EPD TVS Characteristics

The  $\mu$ Clamp3301H is constructed using Semtech’s proprietary EPD technology. The structure of the EPD TVS is vastly different from the traditional pn-junction devices. At voltages below 5V, high leakage current and junction capacitance render conventional avalanche technology impractical for most applications. However, by utilizing the EPD technology, the  $\mu$ Clamp3301H can effectively operate at 3.3V while maintaining excellent electrical characteristics.

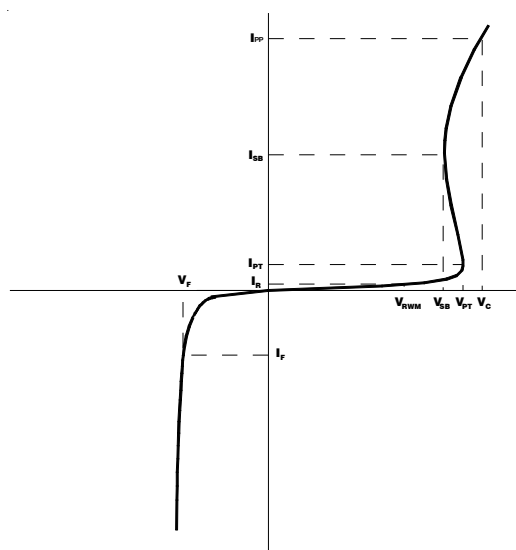
The EPD TVS employs a complex npnp structure in contrast to the pn structure normally found in traditional silicon-avalanche TVS diodes. Since the EPD TVS devices use a 4-layer structure, they exhibit a slightly different IV characteristic curve when compared to conventional devices. During normal operation, the device represents a high-impedance to the circuit up to the device working voltage ( $V_{RWM}$ ). During an ESD event, the device will begin to conduct and will enter a low impedance state when the punch through voltage ( $V_{PT}$ ) is exceeded. Unlike a conventional device, the low voltage TVS will exhibit a slight negative resistance characteristic as it conducts current. This characteristic aids in lowering the clamping voltage of the device, but must be considered in applications where DC voltages are present.

When the TVS is conducting current, it will exhibit a slight “snap-back” or negative resistance characteristics due to its structures. This point is defined on the curve by the snap-back voltage ( $V_{SB}$ ) and snap-back

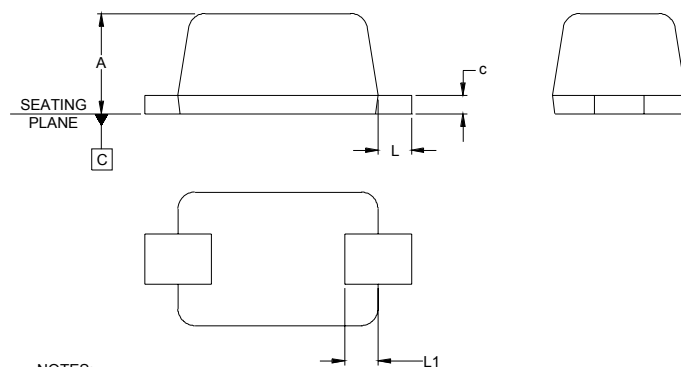
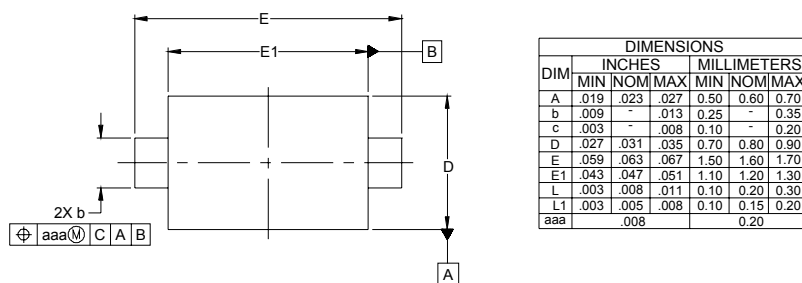
#### Device Schematic & Pin Configuration



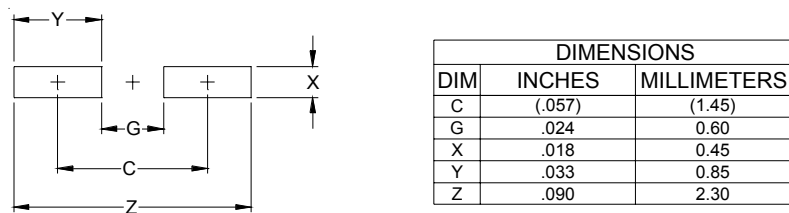
#### EPD TVS IV Characteristic Curve



current ( $I_{SB}$ ). To return to a non-conducting state, the current through the device must fall below the  $I_{SB}$  (approximately <50mA) and the voltage must fall below the  $V_{SB}$  (normally 2.8 volts for a 3.3V device). If a 3.3V TVS is connected to 3.3V DC source, it will never fall below the snap-back voltage of 2.8V and will therefore stay in a conducting state.

**PROTECTION PRODUCTS**
**Outline Drawing - SOD-523**

**NOTES:**

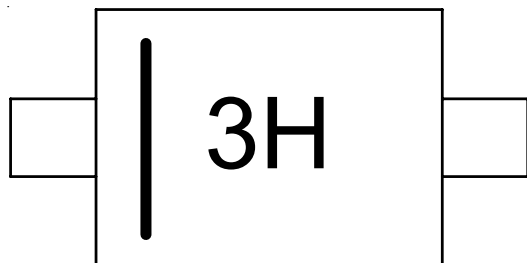
1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. DIMENSIONS "E1" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

**Land Pattern - SOD-523**

**NOTES:**

1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY  
CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR  
COMPANY'S MANUFACTURING GUIDELINES ARE MET

## PROTECTION PRODUCTS

### Marking Code

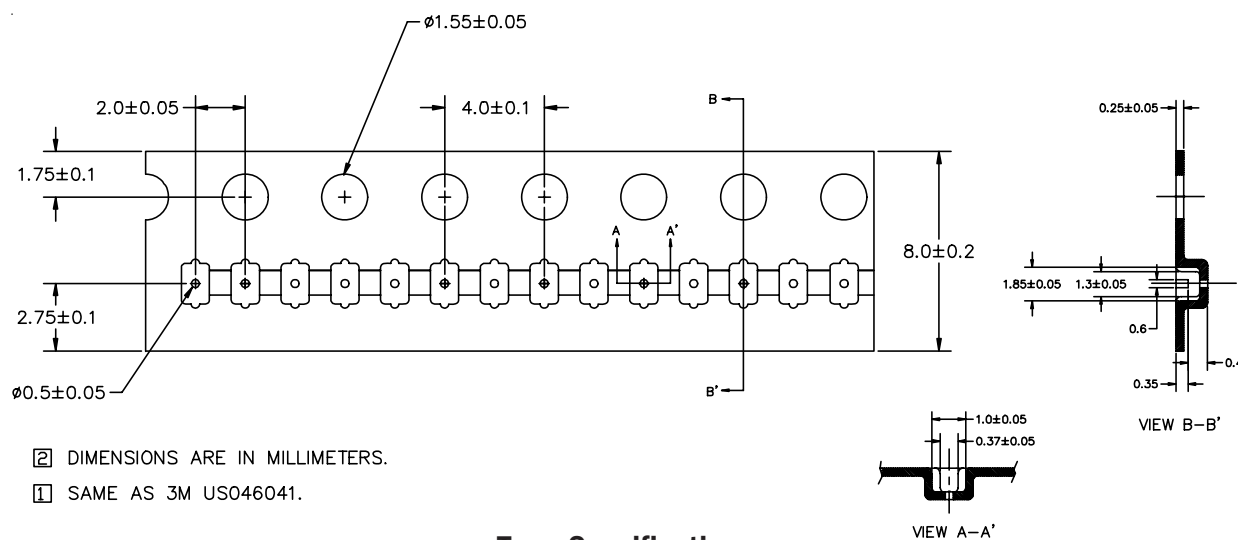


### Ordering Information

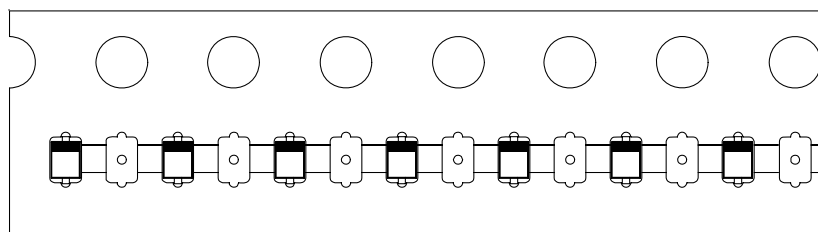
| Part Number     | Working Voltage | Device Marking | Qty per Reel | Reel Size |
|-----------------|-----------------|----------------|--------------|-----------|
| uClamp3301H.TCT | 3.3V            | 3H             | 3,000        | 7 Inch    |

MicroClamp, uClamp and  $\mu$ Clamp are trademarks of Semtech Corporation

### Tape and Reel Specification



### Tape Specifications



### Device Orientation in Tape

**Contact Information**

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